## NSN 5961-01-102-7858

**Fiig:** A110a0

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View Online at https://aerobasegroup.com/nsn/5961-01-102-7858 **Inclosure Material:** Plastic **Overall Length:** 0.870 inches **Overall Height:** 0.200 inches **Overall Width:** 0.310 inches **Component Name And Quantity:** 7 transistor **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor **Voltage Rating In Volts Per Characteristic:** 20.0 collector to base voltage/static/emitter open all transistor and 16.0 collector to emitter voltage/static/base open all transistor and 5.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 20.00 milliamperes source cutoff current all transistor and 100.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 750.0 milliwatts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** Internal junction configuration transistor npn **Terminal Type And Quantity:** 16 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No